

NTE978/NTE978C/NTE978SM Integrated Circuit Dual Timer

Description:

The NTE978 series dual timing circuit is a highly stable controller capable of producing accurate time delays or oscillation. The NTE978 is a dual NTE955. Timing is provided by an external resistor and capacitor for each timing function. The two timers operate independently of each other sharing only V_{CC} and GND. The circuits may be triggered and reset on falling waveforms. The output structures may sink or source 200mA.

Features:

- Direct Replacement for 556 Timers
- Replaces Two 555 Timers
- Timing from Microseconds through Hours
- Operates in both Astable and Monostable Modes
- Adjustable Duty Cycle
- Output can Source or Sink 200mA
- Output and Supply TTL Compatible
- Temperature Stability better than 0.005% per °C
- Normally On and Normally Off Output
- Available in Three Types:
 - NTE978 14-Lead DIP
 - NTE978C 14-Lead DIP (CMOS)
 - NTE978SM SOIC-14 (Surface Mount)

Applications:

- Precision Timing
- Pulse Generation
- Sequential Timing
- Time Delay Generation
- Pulse Width Modulation
- Pulse Position Modulation
- Linear Ramp Generator

Absolute Maximum Ratings:

Supply Voltage, V_{CC}	+18V
Power Dissipation (Note 1), P_D	1620mW
Operating Temperature Range, T_A	0° to +70°C
Storage Temperature Range, T_{stg}	-65° to +150°C
Lead Temperature (During Soldering, 10sec Max), T_L	+260°C

Note 1. For operating at elevated temperatures the device must be derated based on a +150°C maximum junction temperature and a thermal resistance of +77°C/W for NTE978 and NTE978C and +110°C/W for NTE978SM.

Electrical Characteristics: ($T_A = +25^{\circ}\text{C}$, $V_{CC} = +5\text{V}$ to $+15\text{V}$, unless otherwise specified)

Parameter	Symbol	Test Conditions		Min	Typ	Max	Unit
Supply Voltage	V_{CC}			4.5	–	16	V
Supply Current (Each Timer Section)	I_{CC}	Low State, Note 2	$V_{CC} = 5\text{V}$, $R_L = \infty$	–	3	6	mA
			$V_{CC} = 15\text{V}$, $R_L = \infty$	–	10	14	mA
Timing Error, Monostable Initial Accuracy		$R_A = 1\text{k}$ to $100\text{k}\Omega$, $C = 0.1\mu\text{F}$, Note 3		–	0.75	–	%
Drift with Temperature				–	50	–	ppm/ $^{\circ}\text{C}$
Accuracy over Temperature				–	1.5	–	%
Drift with Supply				–	0.1	–	%/V
Timing Error, Astable Initial Accuracy		$R_A, R_B = 1\text{k}$ to $100\text{k}\Omega$, $C = 0.1\mu\text{F}$, Note 3		–	2.25	–	%
Drift with Temperature				–	150	–	ppm/ $^{\circ}\text{C}$
Accuracy over Temperature				–	3.0	–	%
Drift with Supply				–	0.30	–	%/V
Trigger Voltage	V_T	$V_{CC} = 15\text{V}$		4.5	5.0	5.5	V
		$V_{CC} = 5\text{V}$		1.25	1.67	2.0	V
Trigger Current	I_T			–	0.2	1.0	μA
Reset Voltage	V_R	Note 4		0.4	0.5	1.0	V
Reset Current	I_R			–	0.1	0.6	mA
Threshold Current	I_{TH}	$V_{TH} = V_{\text{Control}}$, Note 5		–	0.03	0.1	μA
		$V_{TH} = 11.2\text{V}$		–	–	250	nA
Control Voltage Level and Threshold Voltage	V_{CL} V_{TH}	$V_{CC} = 15\text{V}$		9	10	11	V
		$V_{CC} = 5\text{V}$		2.6	3.33	4.0	V
Pin1, Pin13 Leakage Output High	I_{dis}			–	1	100	nA
Pin1, Pin13 Saturation Output Low		Note 6	$V_{CC} = 15\text{V}$, $I = 15\text{mA}$	–	180	300	mV
			$V_{CC} = 4.5\text{V}$, $I = 4.5\text{mA}$	–	80	200	mV
Output Voltage Drop (Low)	V_{OL}	$V_{CC} = 15\text{V}$	$I_{SINK} = 10\text{mA}$	–	0.1	0.25	V
			$I_{SINK} = 50\text{mA}$	–	0.4	0.75	V
			$I_{SINK} = 100\text{mA}$	–	2.0	2.75	V
			$I_{SINK} = 200\text{mA}$	–	2.5	–	V
		$V_{CC} = 5\text{V}$	$I_{SINK} = 5\text{mA}$	–	0.25	0.35	V
Output Voltage Drop (High)	V_{OH}	$V_{CC} = 15\text{V}$	$I_{SOURCE} = 200\text{mA}$	–	12.5	–	V
			$I_{SOURCE} = 100\text{mA}$	12.75	13.3	–	V
		$V_{CC} = 5\text{V}$		2.75	3.3	–	V
Rise Time of Output	t_{OLH}			–	100	–	ns
Fall Time of Output	t_{OHL}			–	100	–	ns
Matching Characteristics Initial Timing Accuracy		Note 7		–	0.1	2.0	%
Timing Drift with Temperature				–	± 10	–	ppm/ $^{\circ}\text{C}$
Drift with Supply Voltage				–	0.2	0.5	%/V

Note 7. Matching characteristics refer to, the difference between performance characteristics of each timer section.

